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Tunable directional thermal emission using a phase change material-based multilayer structure

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The directional and spectral control of thermal emission with a tunable angular range is essential for realizing next-generation smart thermal emitters. However, existing photonic strategy-based thermal emitters manage thermal emission only over a fixed angular range. Here, we present a lossless chalcogenide phase change material (PCM)-based tunable multilayer structure as a thermal emitter for actively regulating angular selectivity in thermal emission. We develop a tunable multilayer stack with a thickness of 1.35 μm by layering alternating thin films of SiO_2 and a high-crystallization-temperature PCM, such as Sb_2S_3 . The principle underlying the proposed tunable directional control of thermal emission relies on the tunable Brewster mode within the SiO_2 – Sb_2S_3 multilayer cavity. For p -polarized light, the cavity exhibits maximum emissivity across a broad spectral band (10–18 μm) around the Brewster angle. In particular, a peak emissivity of over 95% is achieved in this broad spectral band at the Brewster angle. The angular range of maximum thermal emission can be tuned through the non-volatile structural phase transition property of Sb_2S_3 , while maintaining a constant spectral bandwidth. Moreover, we demonstrate electrically controlled thermal emission using a microheater-integrated Sb_2S_3 – SiO_2 multilayer cavity. This photonic structure could serve as a versatile, tunable, lithography-free platform to dynamically control the angular range of directional thermal emission and emissivity for emerging applications of thermal emitters.

New concepts

Since thermal emission is a broadband phenomenon, controlling the directionality (angular selectivity) of emitted far-field thermal radiation presents a fundamental challenge. Although directional control of thermal emission has been achieved using various photonic structures, tunable angular selectivity has not been extensively studied. Recently, the thermally tunable angular selectivity of broadband directional thermal emission was demonstrated using InAs-based gradient epsilon-near-zero (ENZ) materials (*Nano Lett.*, 2025, 25, 8064–8071). However, InAs is a volatile material that shows low refractive index variation with temperature. In this work, we propose a multilayer structure based on a chalcogenide phase change material (PCM), such as Sb_2S_3 , to enable tunable directional control of thermal emission. Sb_2S_3 is a non-volatile material that exhibits a substantial change in refractive index by switching from amorphous to crystalline phase through thermal treatment. Consequently, the proposed photonic structure provides greater angular tunability compared to existing methods. This is the first demonstration of a PCM-based tunable multilayer cavity for adjustable directional control of thermal emission. Additionally, we report electrically controlled thermal emission using a compact microheater integrated cavity. Achieving angular-selective thermal emission across a broad spectrum is vital for numerous applications, especially in daytime radiative cooling.

1. Introduction

Thermal radiation is a broadband phenomenon that presents a fundamental challenge in controlling the directionality (angular selectivity) of the emitted far-field thermal radiation.¹ The directional and spectral control of thermal emission across a wide bandwidth is crucial for applications such as thermal camouflaging, solar heating, radiative cooling, and waste heat recovery.^{2–7} Notably, angular selective thermal emission has been explored as an additional design factor for daytime radiative cooling, with theoretical studies⁸ demonstrating improved cooling performance, especially in humid conditions where atmospheric transmission is reduced. The introduction of selectivity, whether spectral or angular, aims to engineer the emissivity of the thermal emitter to maximize net radiated thermal emission. The thermal emitter exhibits high emissivity at wavelengths and angles with

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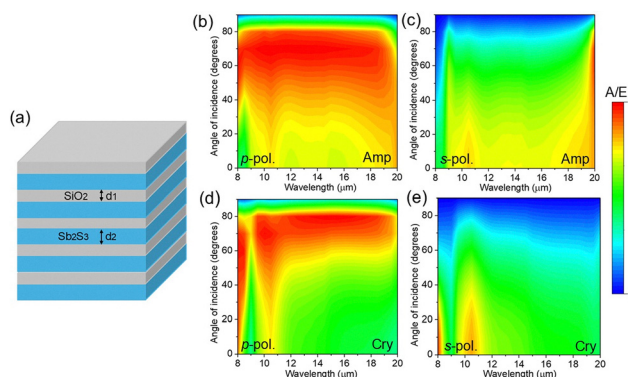
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Here, we experimentally demonstrate a tunable angular range for broadband directional thermal emission using a chalcogenide phase change material (PCM)-based tunable multilayer structure. PCMs are thermally tunable optical materials that provide stable and power-efficient multistate and non-volatile tunability by altering their structural phase between amorphous and crystalline.^{28,29} We utilize the tunable Brewster

According to Kirchhoff's law of thermal radiation, the emissivity (E) for each frequency, polarization, and angle of incidence equals the absorptivity (A), meaning $E(\omega, \theta) = A(\omega, \theta)$. The developed $\text{SiO}_2\text{-Sb}_2\text{S}_3$ multilayer is opaque to wavelengths greater than $5\text{ }\mu\text{m}$ because SiO_2 layers are not transparent. This indicates that absorptivity can be controlled by managing angular reflection (R), resulting in $A = 1 - R$. Therefore, angular thermal emission can be calculated by determining angular reflection. The principle behind the proposed tunable directional control of thermal emission is based on the tunable Brewster mode in the $\text{SiO}_2\text{-Sb}_2\text{S}_3$ multilayer. According to the Brewster mode concept, p -polarized light should not reflect at the Brewster angle, defined as $\theta_B = \tan^{-1}(\epsilon_2/\epsilon_1)^{1/2}$, where θ_B represents the Brewster angle and (ϵ_2, ϵ_1) are the dielectric



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3. Results and discussion

3.2. Experimental results

(a) SEM image of the SiO₂/Sb₂S₃ heterostructure. The SiO₂ layer thickness is approximately 100 nm, and the Sb₂S₃ layer thickness is approximately 170 nm. The structure consists of 10 layers.

(b) Transmission spectrum at $\theta = 0^\circ$. The transmission is plotted against wavelength (μm) from 5 to 20. A sharp dip is observed at approximately 4.5 μm .

(c) s-pol reflectance spectra for incident angles of 15, 30, 45, 60, 65, 70, 75, and 80 degrees. The reflectance is plotted against wavelength (μm) from 5 to 20. Multiple resonance peaks are visible, shifting with the incident angle.

(d) p-pol reflectance spectra for incident angles of 15, 30, 45, 60, 65, 70, 75, and 80 degrees. The reflectance is plotted against wavelength (μm) from 5 to 20. The resonance profiles are different from the s-pol case.

To achieve tunable directional control of broadband thermal emission, the cavity is annealed at 280 °C, causing the phase of the Sb_2S_3 layers to transition from amorphous to crystalline. The phase change is further confirmed using X-ray diffraction (XRD) and Raman measurements (see Fig. S2, SI). Fig. 3a and b present the measured p -polarized angular absorption/emissivity spectra of the amorphous and crystalline cavities, respectively. For the amorphous cavity, the peak broadband emissivity

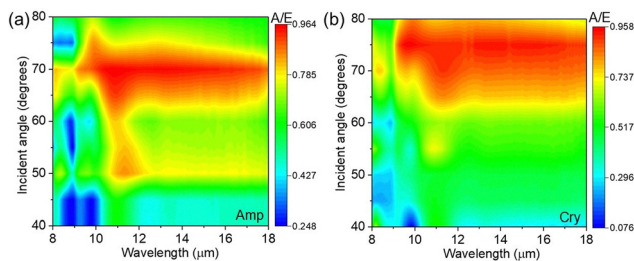


Fig. 3 Measured *p*-polarized angular absorption (A)/emissivity (E) spectrum of the SiO₂-Sb₂S₃ multilayer when the structural phase of Sb₂S₃ is (a) amorphous and (b) crystalline.

is obtained at a Brewster angle of 70°, while the Brewster angle shifts to 75° for the crystalline cavity. Consequently, the angular range of maximum thermal emission changes from 65°–75° to 70°–80° due to the non-volatile phase change of the Sb₂S₃ layers in the cavity from amorphous to crystalline. This indicates that a narrow angular range of directional thermal emission can be tuned, which aligns well with the simulation results. However, a discrepancy below 10 μm exists between the measured and simulated results, as the optical constants used in the simulation are based on literature values. We also conducted polarized angular reflectance measurements using a SiO₂ substrate as a control experiment, as SiO₂ layers in the SiO₂-Sb₂S₃ cavity absorb light above 5 μm (see Fig. S3, SI). As shown, the obtained absorption spectra differ from those of the SiO₂-Sb₂S₃ cavity, rendering directional thermal emission impossible. This confirms that the realized directional thermal emission for *p*-polarization is due to the Brewster effect in the SiO₂-Sb₂S₃ cavity.

We developed a microheater-integrated multilayer cavity to achieve electrically controlled thermal emission. An optical image of the fabricated microheater-integrated multilayer cavity is shown in Fig. 4a, where the Au-based microheater is initially fabricated on a Si substrate using photolithography, metal deposition, and the standard lift-off process, followed by

the deposition of multilayers of Sb₂S₃ and SiO₂. The temperature calibration results of the microheater indicate that the temperature varies linearly with the applied current (see Fig. S4, SI). A custom-designed experimental setup, integrated with the Bruker Fourier-transform infrared (FTIR) spectrometer, is meticulously engineered for high-precision emission measurements at normal incidence (Fig. 4b). This setup incorporates a Cassegrain lens, known for its dual-mirror optical system, which combines a primary parabolic mirror and a secondary hyperbolic mirror to provide a high numerical aperture and efficient light collection over a wide spectral range. The lens is mounted within a specially fabricated, stable lens holder, ensuring precise optical alignment and minimizing potential aberrations or signal losses during measurement. The overall design of the setup is optimized to maximize the signal-to-noise ratio by efficiently collecting and transferring the emitted light, even for samples with low emission intensities. Initially, we measured the emission of the microheater alone to check for any background emission caused by Joule heating and found that the variation in background emission is negligible as the applied current increases (see Fig. S5, SI). We then measured the emission of the microheater-integrated cavity at the same currents and normalized it to the background emission for each current. Fig. 4c shows the normalized thermal emission measured at normal incidence for different applied currents. As observed, the emission intensity gradually increases with the applied current. The emission spectra follow the absorption spectrum of the SiO₂-Sb₂S₃ cavity, measured at normal incidence (inset of Fig. 4c). Significant emission intensity is detected even at an applied current of 80 mA, where the temperature reaches approximately 100 °C, causing the cavity to start emitting. Note that heating below 180 °C does not change the refractive index of the Sb₂S₃ layers. Therefore, the observed emission modulation is solely due to the change in temperature of the microheater. Since the detector is not sensitive enough for longer wavelengths, we cannot extend the emission intensity spectra beyond a 10 μm wavelength.

Tunable directional thermal emission can be further improved by replacing Sb₂S₃ with another lossless phase-change material like Ge₂Sb₂Se₄Te₁ (GSST),³⁵ which offers a higher refractive index contrast than Sb₂S₃ (see Fig. S6, SI). Since the used direct annealing method only changes the phase of the Sb₂S₃ layers from amorphous to crystalline, reconfigurable directional emission cannot be achieved. However, PCM-based multilayer structures can be reconfigured using electrical and optical pulses through a melt-quench process.^{36–38} Notably, optical switching enables the proposed thermal emitter to support multi-state switching, allowing for reconfigurable directional thermal emission with multiple cycles, along with a microheater that operates below 180 °C solely for thermal radiation control. The measured reflectance spectrum of the cavity, spanning from visible to near-infrared wavelengths, shows that the cavity has two tunable photonic bandgaps (see Fig. S1, SI). The cavity either reflects or transmits light below 5 μm; thus, absorption is negligible below this wavelength, while thermal emission occurs above 5 μm, which is crucial for developing an efficient daytime radiative cooling coating. Compared to

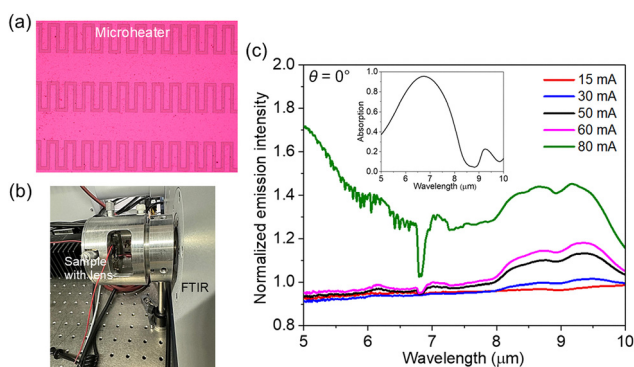


Fig. 4 (a) Optical microscope image of the fabricated microheater-integrated SiO₂-Sb₂S₃ cavity. The array of rectangular patterns represents the Au-based microheater, while the pink color indicates the SiO₂-Sb₂S₃ cavity. (b) Image of the custom-designed experimental setup integrated with the Bruker FTIR. (c) Measured normalized emission intensity at normal incidence for different applied currents; the inset shows the absorption spectrum of the SiO₂-Sb₂S₃ cavity measured at normal incidence.



existing thermo-optic-based tunable directional thermal emitters,²⁷ the proposed device offers non-volatile, tunable directional control with a broadband response.

4. Conclusions

We demonstrated the tunable directional control of thermal emission using a SiO₂-Sb₂S₃ multilayer-based tunable thermal emitter. We showed that the angular range of maximum emissivity over a broad spectral band can be controlled by utilizing the Brewster angle effect of the SiO₂-Sb₂S₃ multilayer cavity. More importantly, this angular range can be adjusted by leveraging the non-volatile structural phase transition property of Sb₂S₃. Furthermore, we demonstrated that thermal emission can be electrically controlled using a compact microheater-integrated SiO₂-Sb₂S₃ multilayer cavity. This lithography-free active photonic platform has the potential to serve as a dynamically tunable thermal emitter for controlling the directionality of broadband thermal emission.

Author contributions

KVS designed the thermal emitter, performed the simulation, fabricated and characterized the samples, collected and analyzed the results, prepared figures, and wrote the original manuscript draft; QYSW performed FTIR measurements and emission measurements, and collected and analyzed the results; SJ fabricated and characterized the samples; RS corrected the original manuscript; JT initiated and supervised the project and corrected the original manuscript. All the authors contributed to the writing of the manuscript.

Conflicts of interest

The authors declare that they have no conflict of interest.

Data availability

The data supporting this article have been included as part of the SI.

Additional experimental and simulation results. See DOI: <https://doi.org/10.1039/d5nh00367a>

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